



SECOND PRELIMINARY AMENDMENT
U.S. Application No. 10/588,659

Attorney Docket No.: Q96380

AMENDMENTS TO THE SPECIFICATION

Please replace paragraph no. [0023] at page 16 of the specification with the following amended paragraph:

In the semiconductor material according to the invention, moreover, a volume resistivity of the semiconductor material is equal to or higher than $10^{-4}\Omega\text{cm}$ and is lower than ~~$10^{-3}\Omega\text{cm}$~~ $10^3\Omega\text{cm}$.

By this structure, the semiconductor material can be applied, as a p-type semiconductor or a hole injecting electrode layer, to a semiconductor device.